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AUG 29 2005

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant(s): Diane C. Boyd, et al.

Examiner: Patricia Ann George

Serial No: 10/725,848

Art Unit: 1765

Filed: December 2, 2003

Docket: YOR920030335US1 (16900)

For: ULTRA-THIN Si MOSFET DEVICE
STRUCTURE AND METHOD OF
MANUFACTURE

Dated: August 29, 2005

Confirmation No.: 3237

Mail Stop Amendment
Commissioner for Patents
United States Patent Office
Alexandria, VA 23313-1450RESPONSE UNDER 37 C.F.R. §§1.111 AND 1.143


Sir:

In response to the Office Action dated August 12, 2005, applicants provisionally elect, without traverse, the subject matter of Group I, i.e., Claims 1-27 for continued prosecution in the above-identified patent application.

CERTIFICATION OF FACSIMILE TRANSMISSION

I hereby certify that this paper is being facsimile transmitted to the Patent and Trademark Office on the date shown below.

Dated: August 29, 2005


Leslie S. Szivos

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